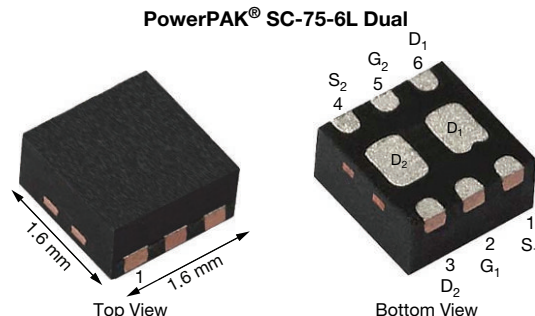


Dual N-Channel 20 V MOSFET



Marking code: CA

PRODUCT SUMMARY	
V_{DS} (V)	20
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 4.5$ V	0.216
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 2.5$ V	0.268
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 1.8$ V	0.375
Q_g typ. (nC)	1.2
I_D (A) ^{a, g}	1.5
Configuration	Dual

ORDERING INFORMATION	
Package	PowerPAK SC-75
Lead (Pb)-free and halogen-free	SiB912DK-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V_{DS}	20	V	
Gate-source voltage	V_{GS}	± 8		
Continuous drain current ($T_J = 150$ °C)	$T_C = 25$ °C	1.5 ^a	A	
	$T_C = 70$ °C	1.5 ^a		
	$T_A = 25$ °C	1.5 ^{a, b, c}		
	$T_A = 70$ °C	1.4 ^{b, c}		
Pulsed drain current	I_{DM}	5		
Continuous source-drain diode current	$T_C = 25$ °C	1.5 ^a		
	$T_A = 25$ °C	0.9 ^{b, c}		
Maximum power dissipation	$T_C = 25$ °C	3.1	W	
	$T_C = 70$ °C	2		
	$T_A = 25$ °C	1.1 ^{b, c}		
	$T_A = 70$ °C	0.7 ^{b, c}		
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) ^{d, e}		260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^{b, f}	$t \leq 5$ s	R_{thJA}	90	115	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	32	40	

Notes

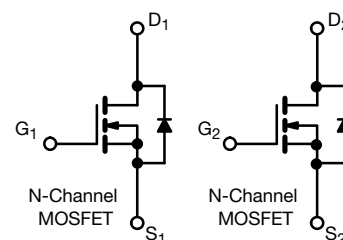
- Package limited
- Surface mounted on 1" x 1" FR4 board
- $t = 5$ s
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Maximum under steady state conditions is 125 °C/W
- Based on $T_C = 25$ °C

FEATURES

- TrenchFET[®] power MOSFET
- Thermally enhanced PowerPAK[®] SC-75 package
 - Small footprint area
 - Low on-resistance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Load switch, PA switch, and battery switch for portable devices
- DC/DC converter


RoHS
COMPLIANT
HALOGEN
FREE



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	20	-	-	V
V _{DS} temperature coefficient	ΔV _{DS} /T _J	I _D = 250 μA	-	22	-	mV/°C
V _{GS(th)} temperature coefficient	ΔV _{GS(th)} /T _J		-	-2	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	0.4	-	1	V
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±8 V	-	-	±100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V	-	-	1	μA
		V _{DS} = 20 V, V _{GS} = 0 V, T _J = 55 °C	-	-	10	
On-state drain current ^a	I _{D(on)}	V _{DS} ≥ 5 V, V _{GS} = 4.5 V	5	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 1.8 A	-	0.180	0.216	Ω
		V _{GS} = 2.5 V, I _D = 1.6 A	-	0.223	0.268	
		V _{GS} = 1.8 V, I _D = 0.3 A	-	0.300	0.375	
Forward transconductance ^a	g _{fs}	V _{DS} = 10 V, I _D = 1.8 A	-	3	-	S
Dynamic ^b						
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	-	95	-	pF
Output capacitance	C _{oss}		-	24	-	
Reverse transfer capacitance	C _{rss}		-	11	-	
Total gate charge	Q _g	V _{DS} = 10 V, V _{GS} = 8 V, I _D = 1.8 A	-	2	3	nC
		V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 1.8 A	-	1.2	1.8	
			Gate-source charge	Q _{gs}	-	
Gate-drain charge	Q _{gd}	-	0.15	-		
Gate resistance	R _g	f = 1 MHz	0.5	2.5	5	Ω
Turn-on delay time	t _{d(on)}	V _{DD} = 10 V, R _L = 7.1 Ω, I _D ≅ 1.4 A, V _{GEN} = 4.5 V, R _g = 1 Ω	-	5	10	ns
Rise time	t _r		-	10	20	
Turn-off delay time	t _{d(off)}		-	24	36	
Fall time	t _f		-	8	16	
Turn-on delay time	t _{d(on)}	V _{DD} = 10 V, R _L = 7.1 Ω, I _D ≅ 1.4 A, V _{GEN} = 8 V, R _g = 1 Ω	-	2	4	
Rise time	t _r		-	9	18	
Turn-off delay time	t _{d(off)}		-	8	16	
Fall time	t _f		-	7	14	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current ^c	I _S	T _C = 25 °C	-	-	1.5	A
Pulse diode forward current	I _{SM}		-	-	5	
Body diode voltage	V _{SD}	I _S = 1.4 A, V _{GS} = 0 V	-	0.7	1.2	V
Body diode reverse recovery time	t _{rr}	I _F = 1.4 A, di/dt = 100 A/μs, T _J = 25 °C	-	9	18	ns
Body diode reverse recovery charge	Q _{rr}		-	3	6	nC
Reverse recovery fall time	t _a		-	6	-	ns
Reverse recovery rise time	t _b		-	3	-	

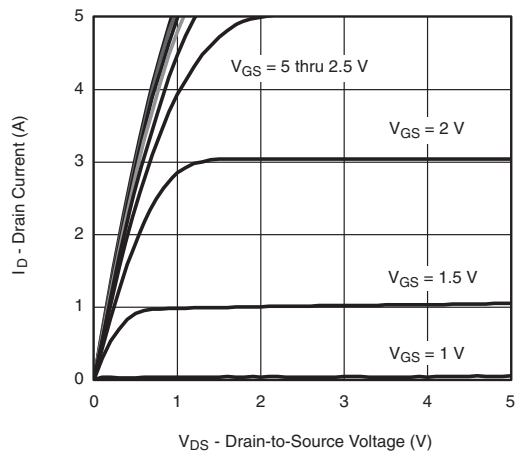
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing
c. Package limited

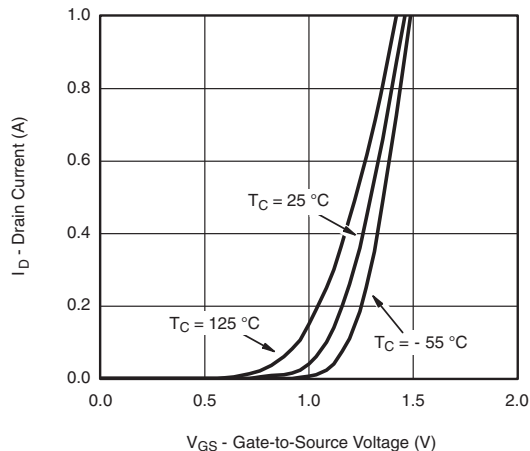
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



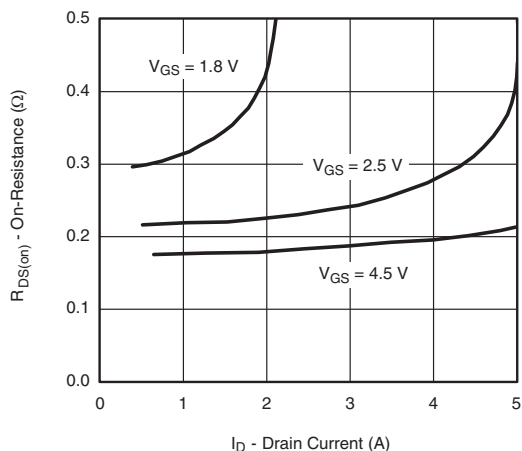
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



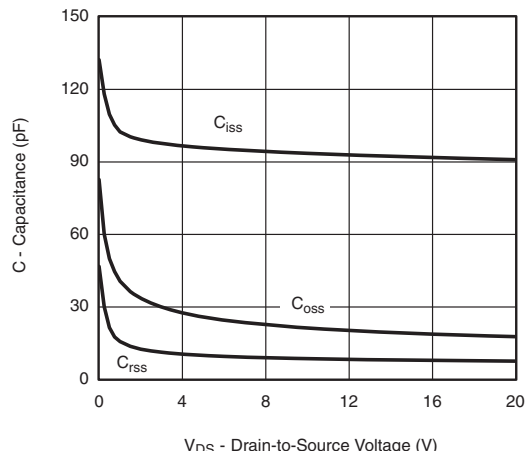
Output Characteristics



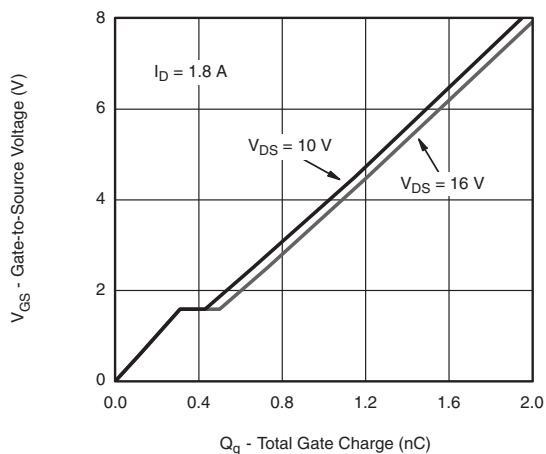
Transfer Characteristics



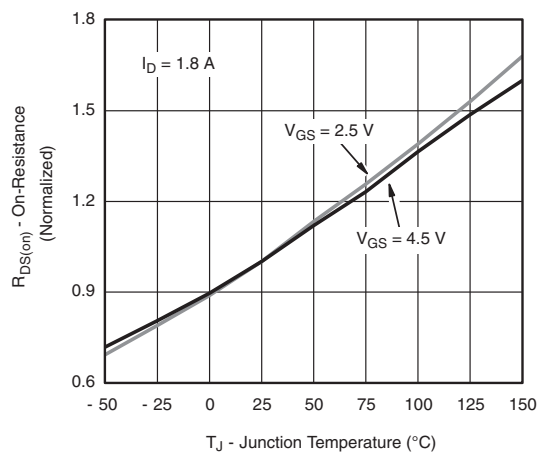
On-Resistance vs. Drain Current and Gate Voltage



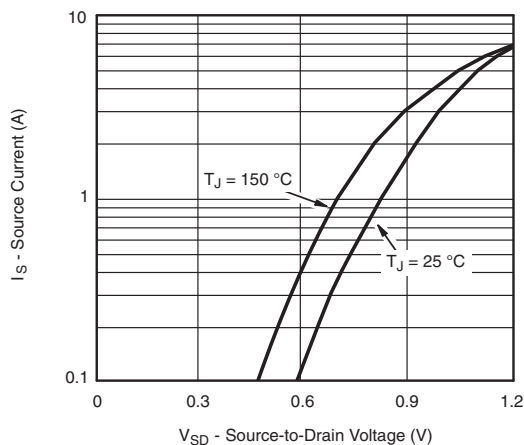
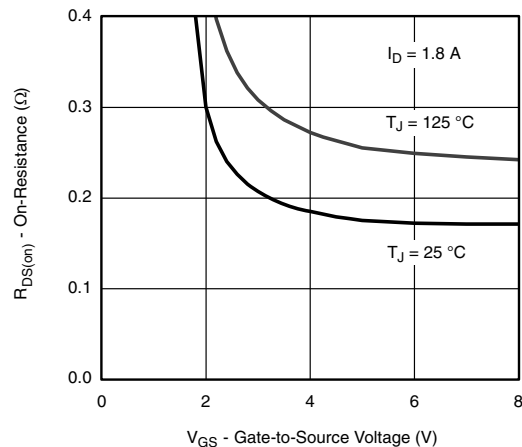
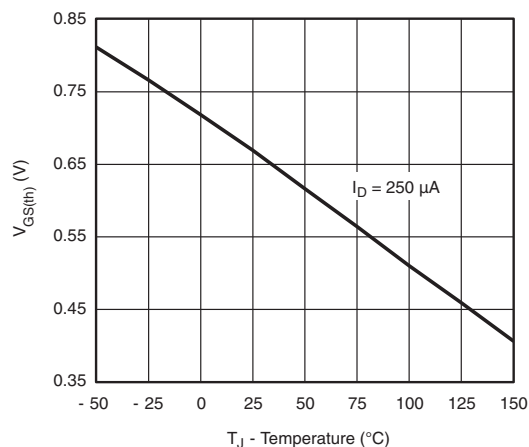
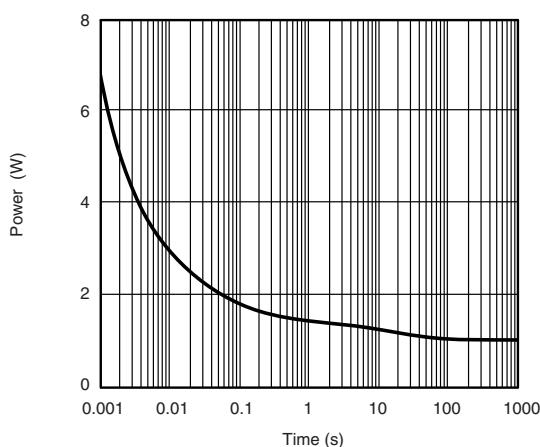
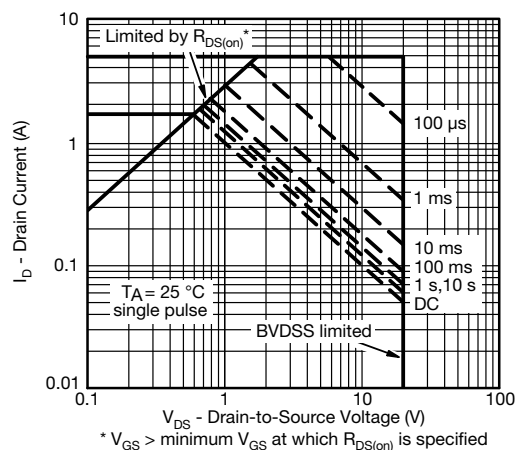
Capacitance

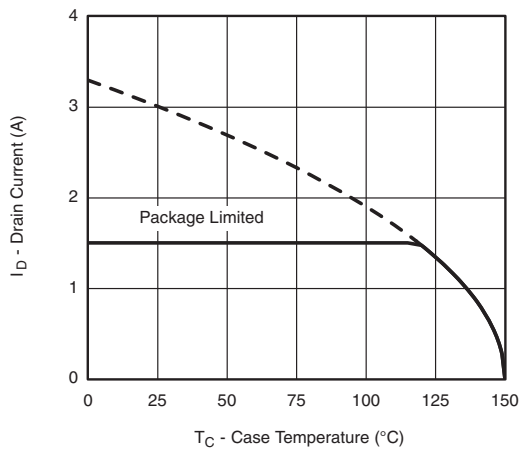
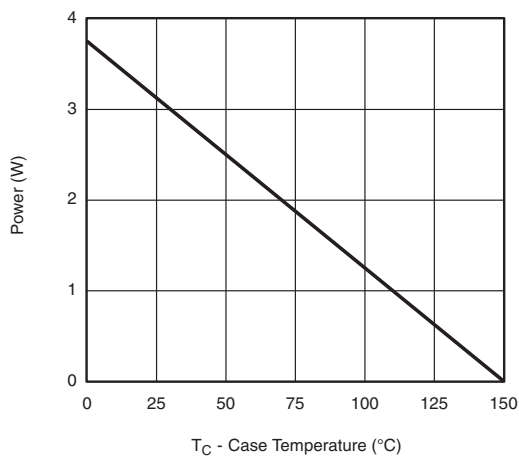
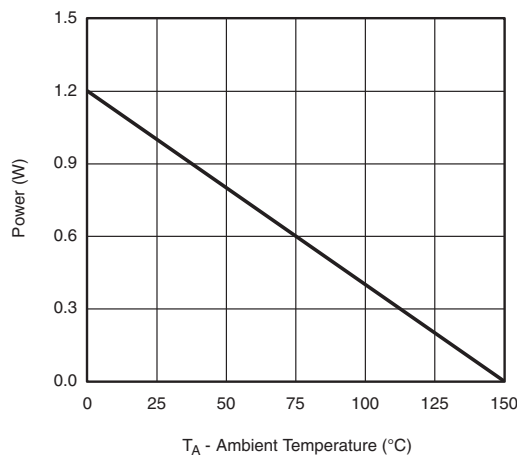


Gate Charge



On-Resistance vs. Junction Temperature

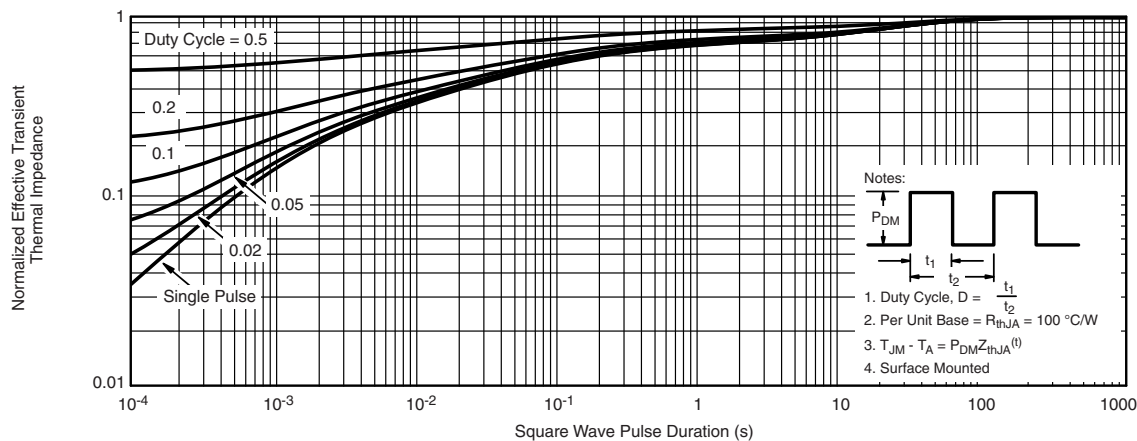
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

Threshold Voltage

Single Pulse Power, Junction-to-Ambient

Safe Operating Area, Junction-to-Case

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Current Derating^a

Power Derating, Junction-to-Case

Power Derating, Junction-to-Ambient
Note

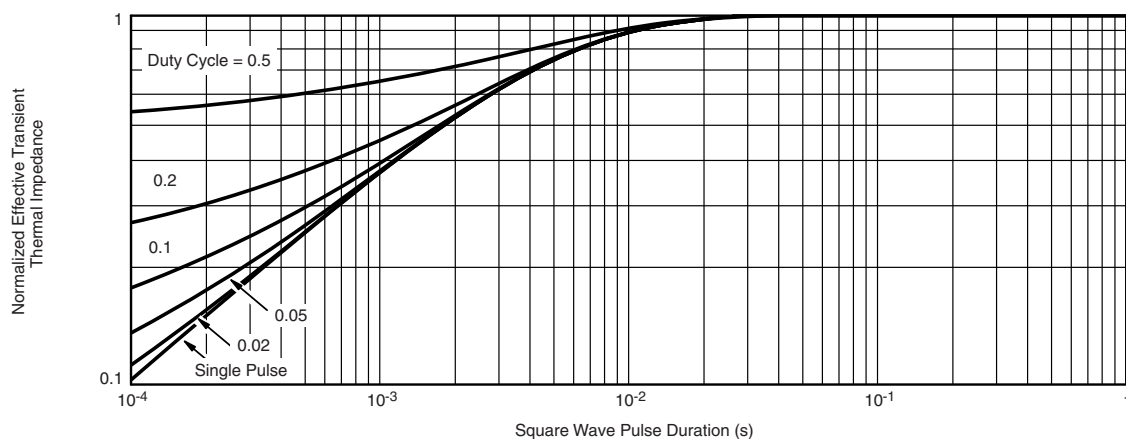
- a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

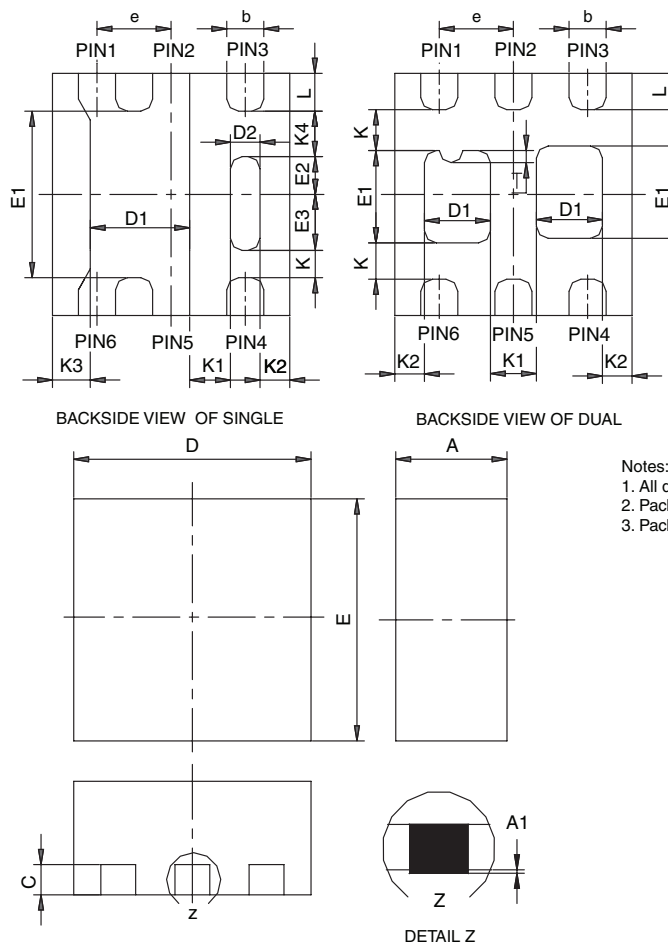


Normalized Thermal Transient Impedance, Junction-to-Case

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PowerPAK® SC75-6L



- Notes:
1. All dimensions are in millimeters
 2. Package outline exclusive of mold flash and metal burr
 3. Package outline inclusive of plating

DIM	SINGLE PAD						DUAL PAD					
	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
A	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.18	0.25	0.33	0.007	0.010	0.013	0.18	0.25	0.33	0.007	0.010	0.013
C	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
D1	0.57	0.67	0.77	0.022	0.026	0.030	0.34	0.44	0.54	0.013	0.017	0.021
D2	0.10	0.20	0.30	0.004	0.008	0.012						
E	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
E1	1.00	1.10	1.20	0.039	0.043	0.047	0.51	0.61	0.71	0.020	0.024	0.028
E2	0.20	0.25	0.30	0.008	0.010	0.012						
E3	0.32	0.37	0.42	0.013	0.015	0.017						
e	0.50 BSC			0.020 BSC			0.50 BSC			0.020 BSC		
K	0.180 TYP			0.007 TYP			0.245 TYP			0.010 TYP		
K1	0.275 TYP			0.011 TYP			0.320 TYP			0.013 TYP		
K2	0.200 TYP			0.008 TYP			0.200 BSC			0.008 TYP		
K3	0.255 TYP			0.010 TYP								
K4	0.300 TYP			0.012 TYP								
L	0.15	0.25	0.35	0.006	0.010	0.014	0.15	0.25	0.35	0.006	0.010	0.014
T							0.03	0.08	0.13	0.001	0.003	0.005

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DWG: 5935

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